

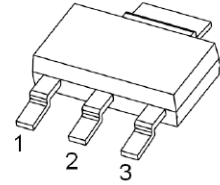
## TRANSISTOR (NPN)

### SOT-223 Plastic-Encapsulate Transistors

#### FEATURES

- For general AF applications
- High collector current
- High current gain
- Low collector-emitter saturation voltage
- AEC-Q101 qualified (Automotive grade with suffix "Q")

**SOT-223**



1. BASE
2. COLLECTOR
3. EMITTER

#### MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CB0</sub>	Collector-Base Voltage	32	V
V <sub>CEO</sub>	Collector-Emitter Voltage	20	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current -Continuous	1	A
P <sub>C</sub>	Collector Power Dissipation	1	W
T <sub>J</sub> , T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55~+150	°C
R <sub>θJA</sub>	Thermal Resistance Junction to Ambient	94	°C/W

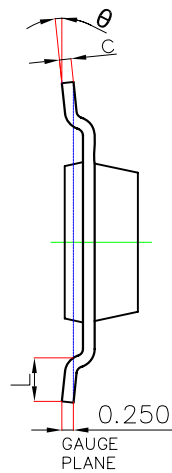
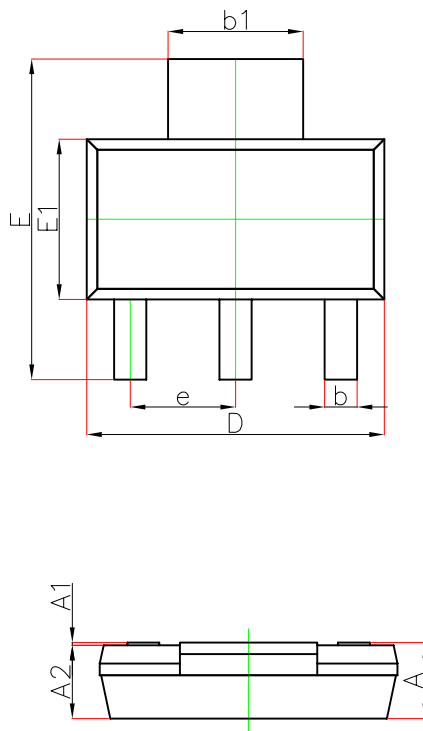
#### ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =100μA, I <sub>E</sub> =0	32			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	20			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =100μA, I <sub>C</sub> =0	5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =25V, I <sub>E</sub> =0			0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0			0.1	μA
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> =1V, I <sub>C</sub> =500mA	85		375	
	h <sub>FE(2)</sub>	V <sub>CE</sub> =1V, I <sub>C</sub> =1A	60			
	h <sub>FE(3)</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =5mA	50			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =1A, I <sub>B</sub> =100mA			0.5	V
Base-emitter voltage	V <sub>BE1</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =5mA			0.68	V
	V <sub>BE2</sub>	V <sub>CE</sub> =1V, I <sub>C</sub> =1A			1	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA, f=100MHz	40			MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =5V, I <sub>E</sub> =0, f=1MHz		38		pF

#### CLASSIFICATION OF h<sub>FE(1)</sub>

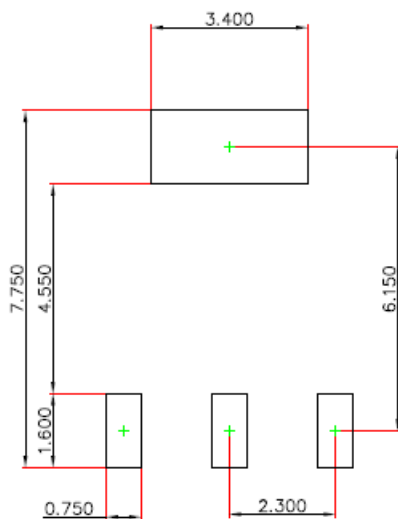
Rank	BCP68-10	BCP68-16	BCP68-25
Range	85-160	100-250	160-375

SOT-223 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	—	1.800	—	0.071
A1	0.020	0.100	0.001	0.004
A2	1.500	1.700	0.059	0.067
b	0.660	0.840	0.026	0.033
$b_1$	2.900	3.100	0.114	0.122
c	0.230	0.350	0.009	0.014
D	6.300	6.700	0.248	0.264
E	6.700	7.300	0.264	0.287
E1	3.300	3.700	0.130	0.146
e	2.300(BSC)		0.091(BSC)	
L	0.750	—	0.030	—
$\theta$	0°	10°	0°	10°

SOT-223 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.050$ mm.
3. The pad layout is for reference purposes only.